LJ CKBP

OSLON® Signal

The OSLON® Signal combine a compact size (small footprint: 3x3mm) with a high efficiency and a electrically insulated thermal pad.









Applications

- Electronic Equipment
- Emergency Vehicle Lighting
- Head-Up Display LED & Laser
- Industrial Automation (Machine Controls, Light Barriers, Vision Controls)
- Traffic Lights
- Transportation, Plane, Ship
- VMS

Features:

- Package: SMD ceramic package with silicone lens

- Chip technology: Thinfilm

Typ. Radiation: 120°

− Color: λ_{dom} = 625 nm (• red)

- Corrosion Robustness Class: 3B

- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)

Ordering Information

Туре	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ Φ_V	Ordering Code	
LJ CKBP-HYKX-47-1	33 82 lm	Q65112A0755	
LJ CKBP-JYKY-36-1	52 97 lm	Q65111A5610	
LJ CKBP-JZKZ-25-1	61 112 lm	Q65111A5609	

Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T_{op}	min. max.	-40 °C 120 °C
Storage Temperature	T _{stg}	min. max.	-40 °C 120 °C
Junction Temperature	T _j	max.	150 °C
Junction Temperature for short time applications*	T _j	max.	175 °C
Forward current T _s = 25 °C	I _F	min. max.	30 mA 1000 mA
Surge Current $t \le 10 \ \mu s; \ D = 0.005 \ ; \ T_s = 25 \ ^{\circ}C$	I _{FS}	max.	2000 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	$V_{\rm ESD}$		8 kV
Reverse current 2)	I _R	max.	50 mA

^{*} The median lifetime (L70/B50) for Tj = 175 $^{\circ}$ C is 100h.

Characteristics

 I_F = 350 mA; T_S = 25 °C

Parameter	Symbol		Values
Peak Wavelength	$\lambda_{\sf peak}$	typ.	632 nm
Dominant Wavelength 3)	$\lambda_{\sf dom}$	min.	612 nm
$I_{\rm F} = 350 \text{ mA}$	40	typ.	625 nm
		max.	636 nm
Spectral Bandwidth at 50% I _{rel,max}	Δλ	typ.	18 nm
Viewing angle at 50% I _v	2φ	typ.	125 °
Forward Voltage 4)	V _F	min.	2.00 V
I _F = 350 mA	·	typ.	2.15 V
		max.	2.60 V
Reverse voltage (ESD device)	$V_{R ESD}$	min.	5 V
Reverse voltage ²⁾	V_R	max.	7 V
$I_R = 5 \text{ mA}$			
Real thermal resistance junction/solderpoint 5)	$R_{thJS\ real}$	typ.	9.6 K / W
	tibo real	max.	10.8 K / W
Electrical thermal resistance junction/solderpoint 5)	R _{thJS elec.}	typ.	6.0 K / W
with efficiency η_e = 38 %	thoo elec.	max.	6.7 K / W



Brightness Groups

Group	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ min. Φ_V	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ max. Φ_V	Luminous Intensity ⁶⁾ I _F = 350 mA typ. I _v
HY	33 lm	39 lm	12 cd
HZ	39 lm	45 lm	14 cd
JX	45 lm	52 lm	16 cd
JY	52 lm	61 lm	19 cd
JZ	61 lm	71 lm	22 cd
KX	71 lm	82 lm	25 cd
KY	82 lm	97 lm	30 cd
KZ	97 lm	112 lm	35 cd

Forward Voltage Groups

Group	Forward Voltage ⁴⁾ I _F = 350 mA min. V _F	Forward Voltage ⁴⁾ I _F = 350 mA max. V _F	
J3	2.00 V	2.15 V	
M3	2.15 V	2.30 V	
Q3	2.30 V	2.45 V	
T3	2.45 V	2.60 V	

Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength 3)
	$I_{F} = 350 \text{ mA}$	$I_F = 350 \text{ mA}$
	min.	max.
	$\lambda_{\sf dom}$	$\lambda_{\sf dom}$
2	612 nm	616 nm
3	616 nm	620 nm
4	620 nm	624 nm
5	624 nm	628 nm
6	628 nm	632 nm
7	632 nm	636 nm

Group Name on Label

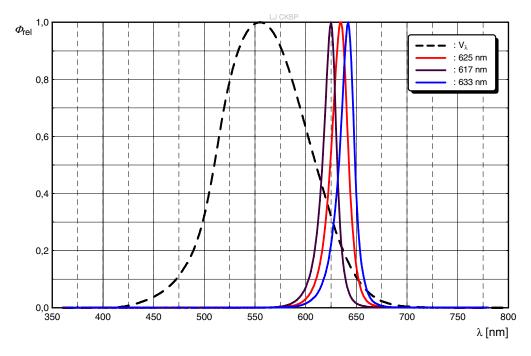
Example: HY-2-J3

Brightness	Wavelength	Forward Voltage
HY	2	J3



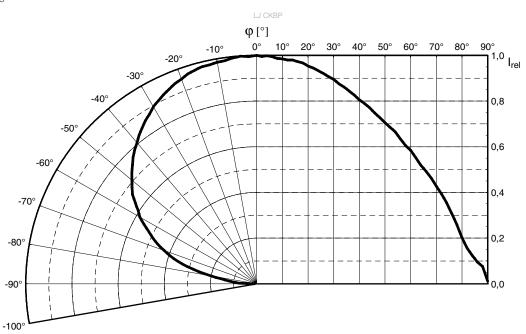
Relative Spectral Emission 6)

$$\Phi_{rel}$$
 = f (λ); I $_F$ = 350 mA; T $_S$ = 25 °C



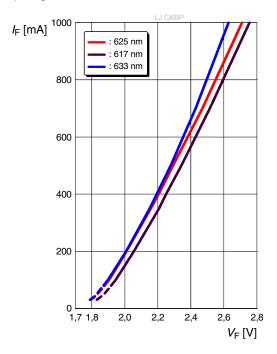
Radiation Characteristics 6)

$$I_{rel} = f(\phi); T_S = 25 °C$$



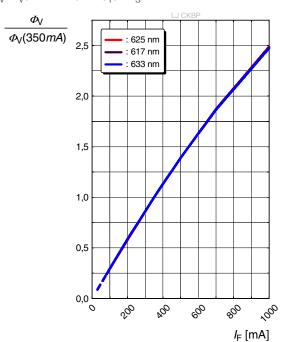
Forward current 6), 7)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



Relative Luminous Flux 6), 7)

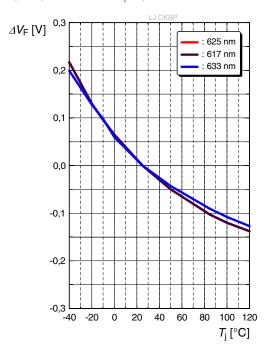
$$\Phi_{V}\Phi_{V}(350 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ °C}$$





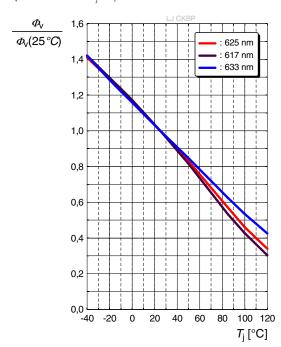
Forward Voltage 6)

$$\Delta V_F = V_F - V_F (25 \text{ °C}) = f(T_j); I_F = 350 \text{ mA}$$



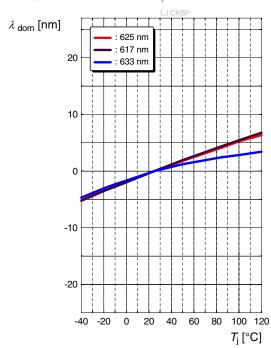
Relative Luminous Flux 6)

$$\Phi_{v}/\Phi_{v}(25 \text{ °C}) = f(T_{i}); I_{F} = 350 \text{ mA}$$



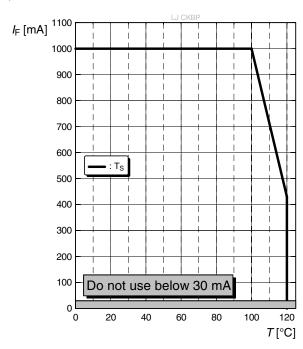
Dominant Wavelength 6)

$$\Delta\lambda_{dom} = \lambda_{dom} - \lambda_{dom}(25 \text{ °C}) = f(T_j); I_F = 350 \text{ mA}$$



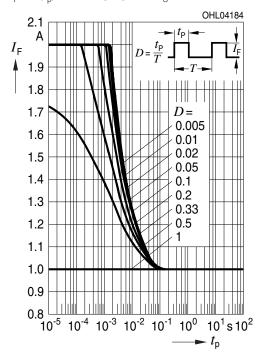
Max. Permissible Forward Current

 $I_F = f(T)$



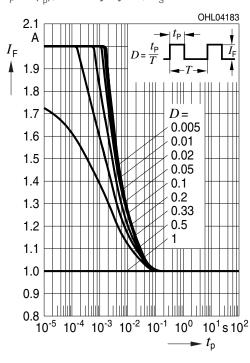
Permissible Pulse Handling Capability

 $I_F = f(t_D)$; D: Duty cycle; $T_S = 25 \, ^{\circ}\text{C}$

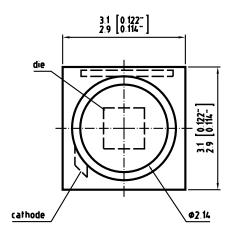


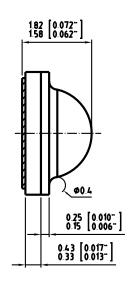
Permissible Pulse Handling Capability

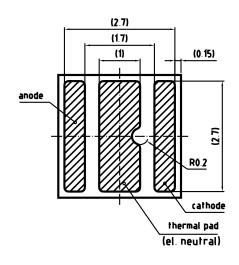
 $I_{_{\rm F}}$ = f(t $_{_{
m D}}$); D: Duty cycle; $T_{_{
m S}}$ = 85 °C



Dimensional Drawing 8)







C63062-A4226-A10..-01

Further Information:

Approximate Weight: 25.0 mg

Package marking: Cathode

Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

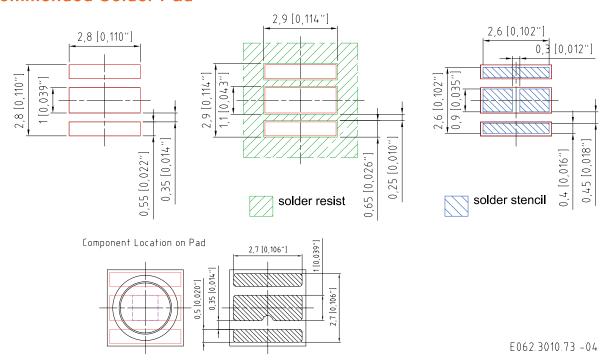
60068-2-43)

ESD advice: The device is protected by ESD device which is connected in parallel to the

Chip.



Recommended Solder Pad 8)

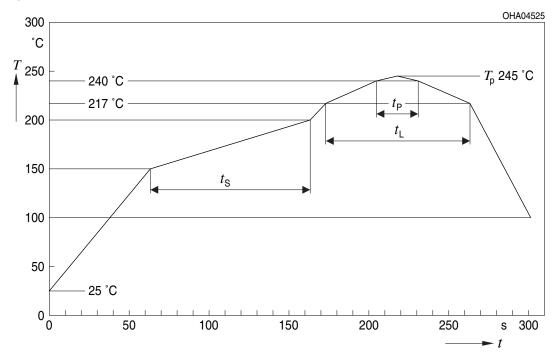


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



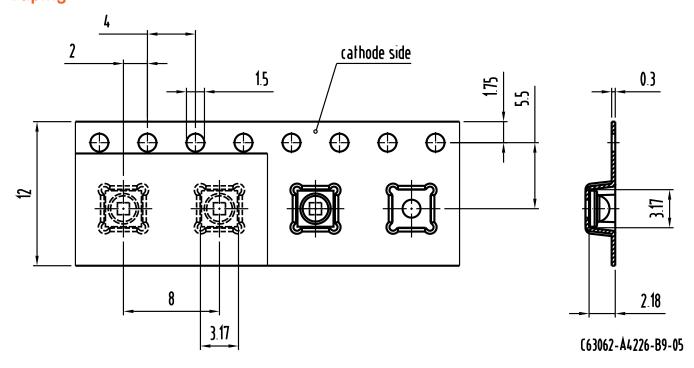
Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t _s	t _s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T_{P}		245	260	°C
Time within 5 °C of the specified peak	t _P	10	20	30	S
temperature T _P - 5 K					
Ramp-down rate*			3	6	K/s
T _P to 100 °C					
Time				480	S
25 °C to T _P					

All temperatures refer to the center of the package, measured on the top of the component



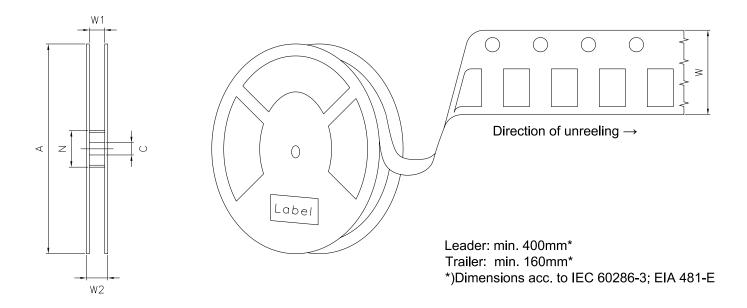
^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 8)





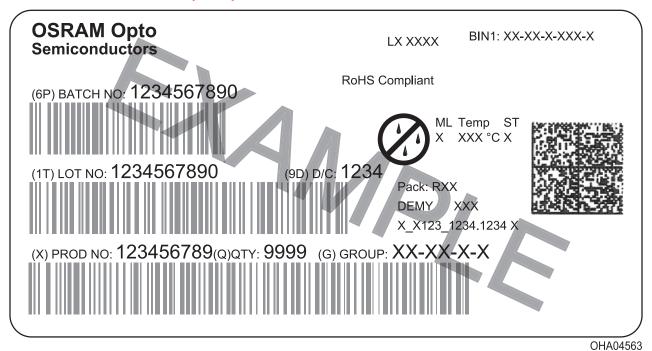
Tape and Reel 9)



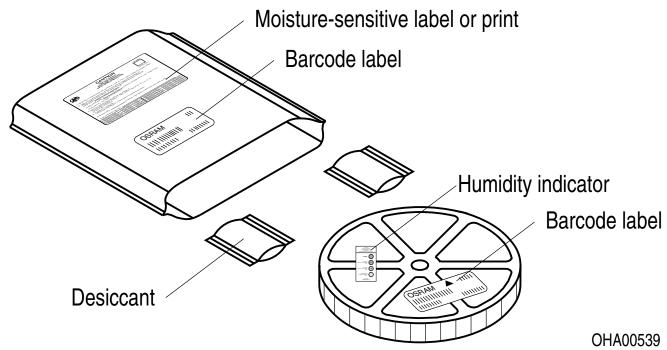
Reel Dimensions

Α	W	N_{\min}	W ₁	$W_{2\text{max}}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	600

Barcode-Product-Label (BPL)



Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Type Designation System

Wavelength (λ _{dom} typ.) B: 470 T: 528 Y: 587 J: 625 V: 505	nm blu nm true nm yell nm red	e green Iow	CIE 193 ⁴ CB: c CY: c	ordinates acco I/Emission colo olor on deman olor on deman Itra white	or: nd blue	
L: Ligh emit diod	ting /			(cera	/pe RAMOS, OSL amic), OSLON apact	
L	В		C		7	Р
L	Б		C			Р
Lead / L: R: K: Q:	2D-Code Trat OSLON Cera next gen(UX:: OSLON Cera ThinGan w/o	mic Material A ffic mic Material A 3 V4, TiO2, HF mic Material A 2D-Code Traff mic Material A	RI-layer IIN fic	lm w/o		
Enc 7: B:	outcouplin	e / Lens Proper g lens (=80°) g lens 120°; la				
	Ch P:	lip Technology power pe	rformance			



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class exempt group (exposure time 10000 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) **Thermal Resistance:** Rth max is based on statistic values (6σ).
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



LJ CKBP

Revision History					
Version	Date	Change			
1.7	2019-07-19	Features Further Information			
1.8	2020-03-23	Schematic Transportation Box Dimensions of Transportation Box			
1.9	2020-08-17	Not for new design			

Published by OSRAM Opto Semiconductors GmbH EU RoHS and China RoHS compliant product Leibnizstraße 4, D-93055 Regensburg www.osram-os.com © All Rights Reserved.

此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准,不含有毒有害物质或元素。

